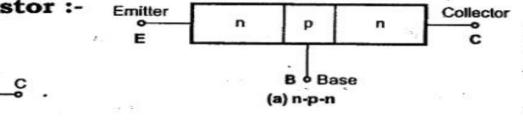
Transistor :-

A transistor consists of two PN junctions. The junctions are formed by Sandwiching either P-type or N-type semiconductor layers between a pair of opposite types as shown below. Transistors are of two types.

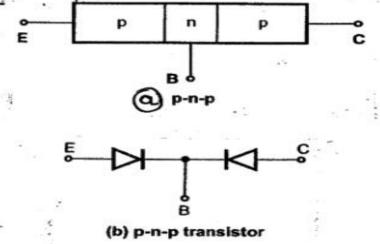
1) NPN Transistor :-

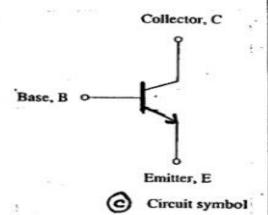


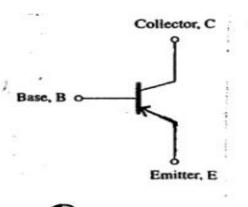
n-p-n transistor

Fig. Two-diode transistor analogy

2) PNP Transistor :-







Transistor Terminals:

Transistor terminals are Emitter, Base & Collector.

Emitter (E):-

- Emitter is heavily doped than other two regions. Its function is to supply majority carriers (either electrons or holes) to the other two regions.
- Emitter is always forward biased w.r.to base.

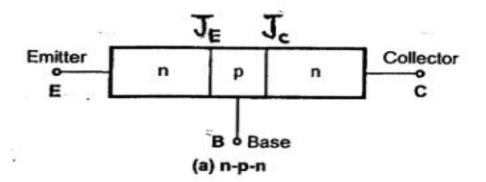
Base (B):-

- It is the middle region that forms two P-N junctions in the transistor.
- The base is lightly doped & much thinner than the emitter & collector region.

Collector (C):-

- It is a region situated in the other side of transistor(i.e. the side opposite to the emitter), which collects charge carriers(i.e. holes & electrons).
- The collector of a transistor is always larger than the emitter &

Transistor Junctions :-



The transistor has two PN junctions $J_E \& J_C$ as shown in figure. The junction J_E is a junction between emitter & base regions. Thus it is known as emitter-base junction. (Forward Biased).

Similarly, the junction J_c is a junction between collector & base regions. Thus it is known as Collector-base junction. (Reversed Biased).

Thus transistor is like two PN junction diodes connected back to back as shown in figure 2.

Transistor operation :-

i) Operation of NPN transistor :-

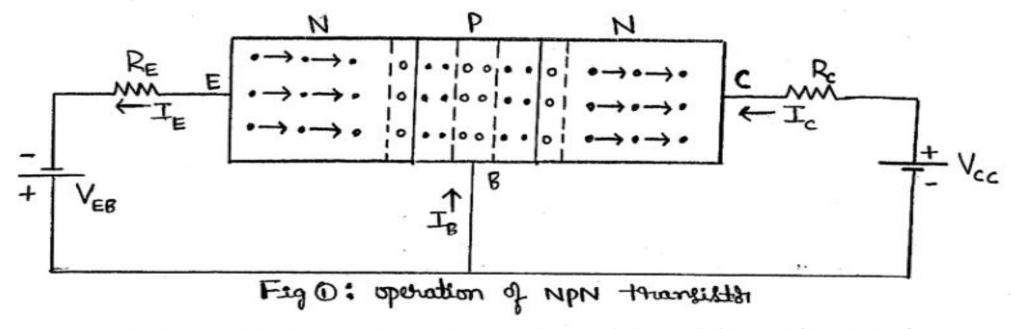


Figure 1 shows an NPN transistor biased in active mode.

In NPN transistor current is due to the movement of free electrons. The emitter to base of a transistor is forward biased & collector to base junction is reversed biased.

- When V_{EB} is greater than barrier potential (Vγ), emitter to base junction is forward biased causes the free electons in the N-type emitter to flow towards the base region. This constitutes the emitter current I_E.
- ❖ As base is lightly doped, only few electrons combine with the holes & constitute base current I_B. Thus most of the electrons will diffuse to the collector region & constitutes collector current I_C.
- There is another component of collector current due to thermally generated carriers. This current component is called reverse saturation current & is quite small.
- ❖ The emitter current is given by $I_E = I_B + I_C$

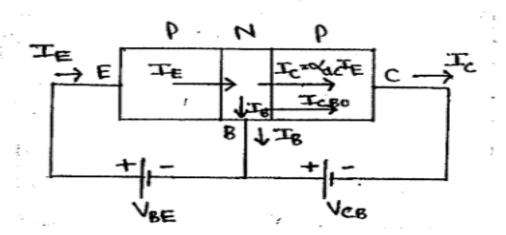
Transistor Currents :- (PNP)

Sketch & explain the current components crossing each junction of a transistor biased in the active region.

Jan-04,6M, Jan-03,5M

With a neat sketch, clearly show the various current components in a PNP transistor & hence establish the relevant equations.

June-04,6M Jan-05,10M Jan-06,7M Jan-07,6M



- * In Fig O, the Coolerst Flowing into the emitter tominal is helpoted to as a emitter Cultert 'IE'.
- * Base Cushert 'I's a Collector Cushert 'I' both flow out of the Harriston, while 'I' flow into the thansiets.

$$T^{\mathsf{E}} = T^{\mathsf{B}} + T^{\mathsf{C}} \longrightarrow 0$$

* Almost all of emitter custient 'I' choses to the collecter of only a Small portion flow out of the base terminal.

Typically 96.1. to 99.5.1. of I'm flow across the collecter to base junction to become collecter custient.

Where \propto_{ac} is the emitted to collected cushent gain & is typically 0.96 to 0.995.

Thue, the Collecter Cushert is almost equal to the emitter Cushert i.e. $I_c \approx I_E$.

* When C-B junction is herebye biased, a very Small Aurebye Saturation Current 'Icro Flores across the junction Called Collector to base Leakage Current 'I're & it is very Small & can be neglected.

$$\boxed{\mathbf{T}_{\mathbf{E}} = \mathbf{T}_{\mathbf{B}} + \mathbf{T}_{\mathbf{C}} \longrightarrow \mathbf{0}}$$

Substituting ear 1 in ear 1

$$\ll_{dc} T_B = T_c - \ll_{dc} T_c$$

Draw a sketch to show the various current components in a NPN transistor & deduce the relation between various current components.

Jan-08,8M

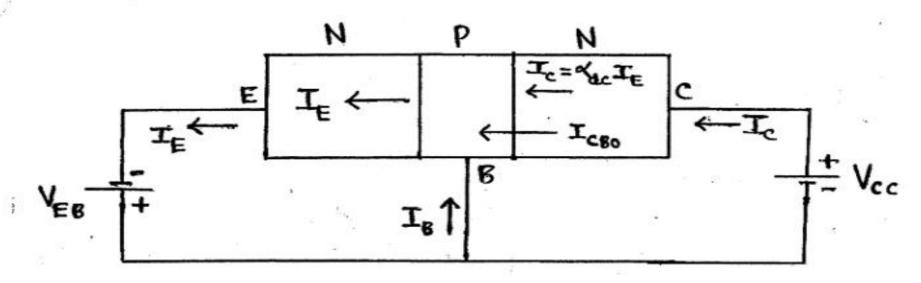


Fig O: Currents in a NPN Huansister

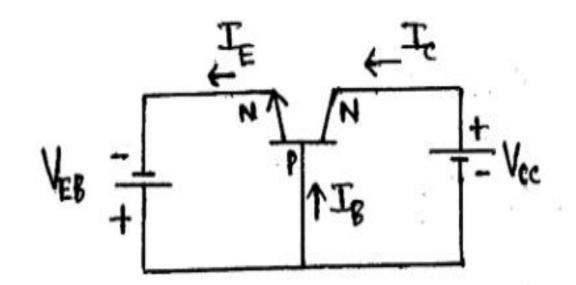


Fig @: Custerts in a NPN thansieth.

* In NPN thankists, electhons are injected into the base. These electrons constitute the emitter current 'TE'.

* Assume that 100 elections are injected into the base hegion. Since the base is very thin, only few elections Say 2 in number, recombine with the hole. This constitute the base custient 'I''s. The tremaining 98 elections Cross the base- Collector, Constituting Collector custient 'I''s.

$$T_{E} = T_{B} + T_{C} \longrightarrow 0$$
KT $A_{dc} = T_{C} \longrightarrow T_{E}$

$$T_c = \sim_{dc} T_E \longrightarrow 3$$

de is the emitter-collecter current poin & is typically 0.96 to 0.995.

* When collected - base junction is Treasurge biased, a redry Small Treasure Saturation Costent (ICBO) Flows across the junction, called Collected to base leakage Costent Topo of it is very Small & can be neglected.

X Substituting eq ① in eq ②, we get $T_c = \propto_{dc} \left[T_B + T_c \right]$ $T_c = \propto_{dc} T_B + \Lambda_{dc} T_c$ $T_c - \sim_{dc} T_c = \sim_{dc} T_B$ $T_c \left[1 - \Lambda_{dc} \right] = \sim_{dc} T_B$

$$I_c = \beta_{ac} I_g$$

* Bac is the base - Collecter Current gain: Typically Bac Tranges from 25 to 300.

Amplification:

Current Amplification:

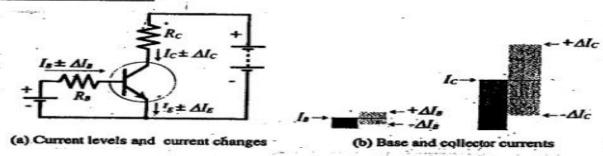


Figure Increasing and decreasing I_8 levels produces much larger changes in I_C and I_P .

 \star A Small Change in the base Current ΔT_B phoduces a large Change in Collecter Current ΔT_C & a large emitted Current Change ΔT_E

i.e.
$$\beta_{dc} = \frac{\Delta T_c}{\Delta T_g}$$

Voltage Amplification:

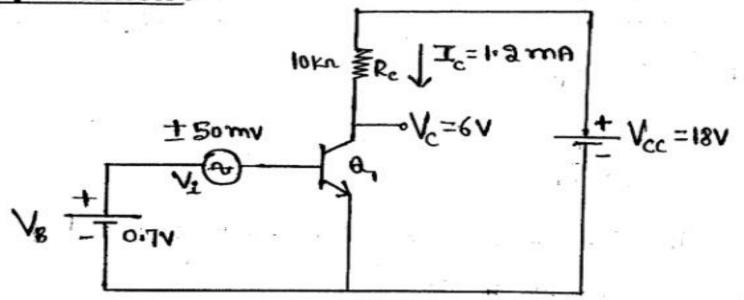
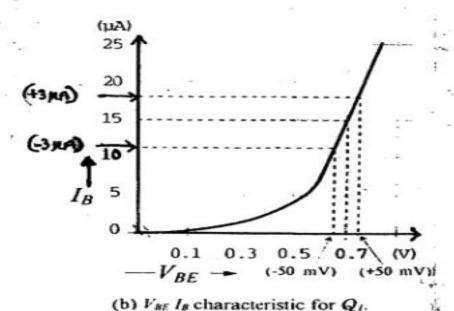


Fig O: Thansista CH

X In Fig (), assume that the translitter Q, has Bac=Bac=80. Note that the 0.74 dc reoltage Source V'g Folward biases the translitter base-emitter junction.

- * An ac Signal 'Vi' in Serie with 'V' provides a ±50mv
- * The Hungister Collecter is Connected to a 184 de rottage Source Vcc via the 10 km Collecter Fregister Rc.
- X If a, has the IBIVBE Characteristics Shown in fig @, the 0.7V level of VB phoduces a 15 up base Custient.
- i.e. IB = 15MA By VB = 0.7V



$$V_{cc} - I_{c}R_{c} - V_{c} = 0$$

$$V_{c} = V_{cc} - I_{c}R_{c}$$

$$+ A_{v} = \frac{V_{o}}{V_{i}} = \frac{\pm 3.44V}{\pm 5000V}$$

Obtain the relationship between α_{dc} & β_{dc}. Jan-11,4M jan-09,4M

WKT
$$I_E = I_B + I_C \longrightarrow 0$$

Dividing on both Sides of eq 10 by Ic

$$\frac{T_E}{T_c} = \frac{T_B}{T_c} + \frac{T_c}{T_c}$$

$$\frac{T_E}{T_B} = \frac{T_E}{T_C} + 1 \longrightarrow 3$$

WKT

$$\beta = I_c | I_B$$
 $\ll = I_c | I_E$
 $| \beta = I_B | I_C$ $| \ll = I_E | I_C$

$$\frac{1}{2} = \frac{1}{2} + 1$$

$$\frac{1}{2} = \frac{1+2}{2}$$

Ey 3 can be written as

Transistor as an Amplifier :-

- A transistor is capable of providing amplification. Explain the basic transistor amplifier with suitable diagrams. June-03,6M
- Show that a transistor could be used as an amplifier.

June-06,5M June-08,6M

A transistor increases the strength of the weak signal acting as an amplifier.

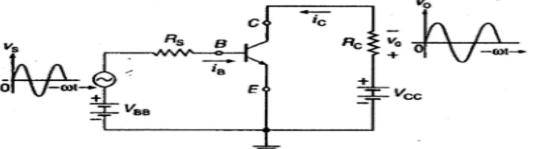


Fig. Basic common emitter amplifier.

Figure shows basic transistor circuit of an amplifier. The supply voltage V_{BB} forward biases the emitter to base junction & V_{CC} reverse biases the collector to base junction. Thus transistor operates in

- active region.
- The magnitude of the ac input signal is such that it always forward bias the emitter to base junction regardless of the polarity of the ac input signal.
- Let During +ve half cycle of the input signal, the forward bias across the emitter to base junction is increased, which increases the collector current. The increased collector current produces greater voltage drop across the resistance 'Rc'.
- ♣ During -ve half cycle of the input signal, the forward bias across the emitter to base junction is decreased, which decreases the

collector current. The decreased collector current produces smaller voltage drop across the resistance R_c .

The small ac input signal produces a large ac output signal. Thus the transistor acts as an amplifier.

TRANSISTOR BIASING :-

The application of dc voltages across the transistor terminals is called biasing.

There are three modes of transistor operation.

Mode	Emitter-base junction	Collector-base junction
Active	Forward	Reverse
Saturation	Forward	Forward
Cut-off	Reverse	Reverse
	Active Saturation	Active Forward Saturation Forward

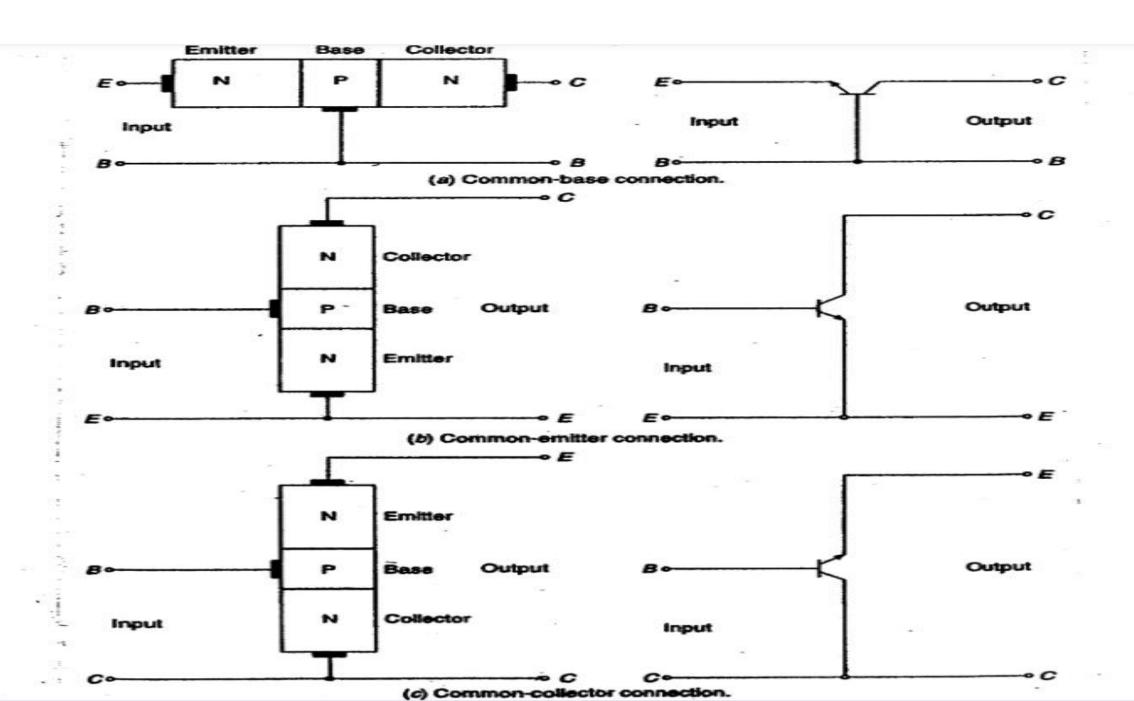
Transistor Configurations :-

Transistor has thre terminals namely **Emitter (E)**, **Base(B)** & **Collector(C)**. When a transistor is connected in a circuit, we require four terminals i.e. two terminals for input and two for output.

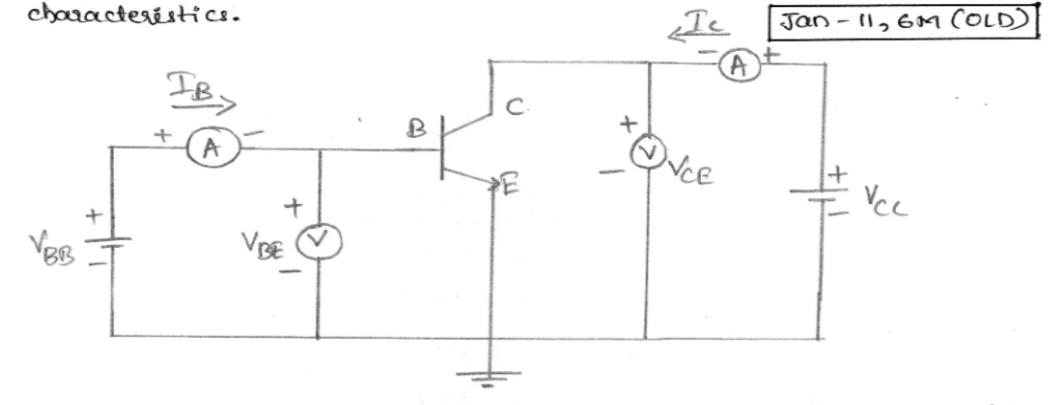
Thus out of three terminals, one terminal is made common to both input and output terminals.

There are three different types of configurations or connection:

- 1) Common-Base Configuration (CB)
- 2) Common-Emitter Configuration (CE)
- 3) Common-Collector Configuration (CC)



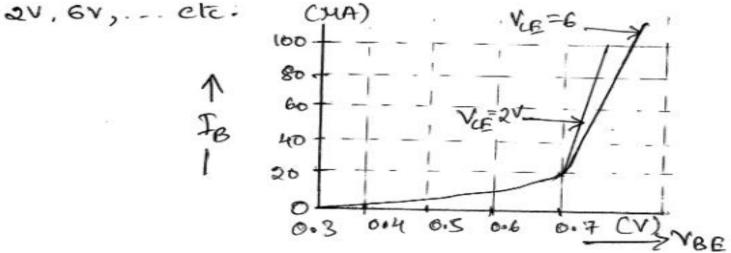
* Explain the input and output characteristics for a ce configuration BIT circuit. Discuss each region on the

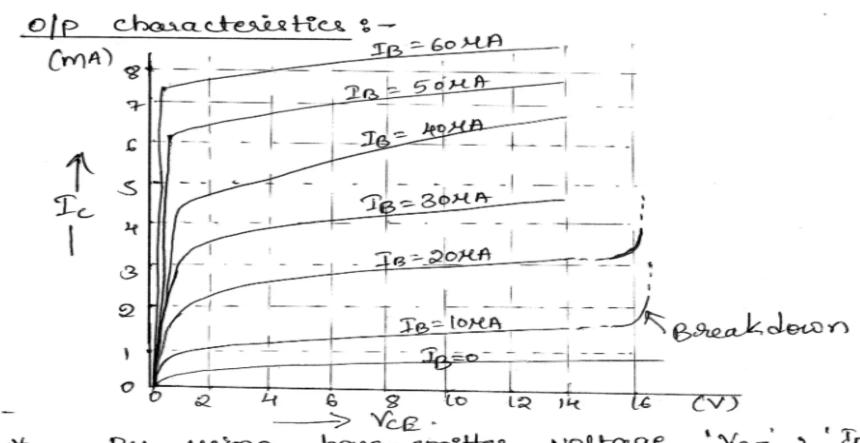


Fig(1) i Oht for determining transister common ensitter characteristics

- * These curves gives the relationship blue the base current IB & the base emitter voltage VBF for a constant collector emitter voltage VcF.
- * To obtain IIP characteristic, the olp voltage 'Vee' is kept constant, IIP voltage 'Vee' is varied in small Intervals & the cossesponding change in IIP current 'Is' is seconded.
- It is then plotted against Ver as shown in fig. .

 The experiment is superated for other value of 'Vcr' say





By using base-emitter voltage 'VBE', 'IB' is maintained constant at several convenient levels.

* V_{cc} ' is varied in suitable steps of at each step T_c value is recorded. The same procedure is repeated for different settings of T_B .

* If we plot a graph with 'Vce' voltage along hosizontal axis & the collector current 'I' along the vertical axis, we shall obtain a olp characteristics as shown in fig 3,

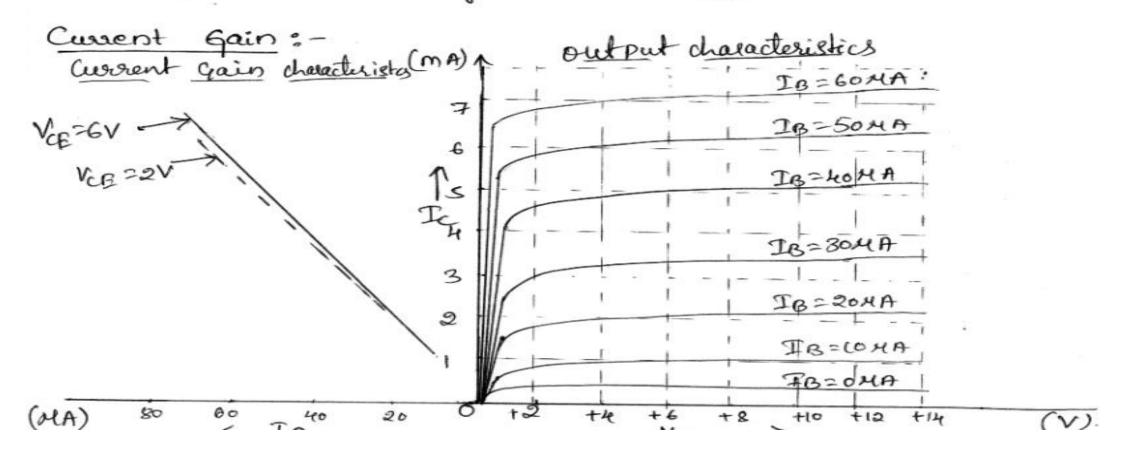
in collector to emitter voltage 'DVcc' to the sesulting change in collector current 'DIC' at constant base current 'Ja'.

$$90 = \frac{\Delta V_{CE}}{\Delta I_{C}} \mid constant$$
IB

(low to sour)

- * The old characteristics curve is divided into 3 regions namely:
- > Saturation region.
- a) Active region.
- 3) cut-off region.
- In saturation region, when the collector to emitter voltage 'V_{CE}' is increased above xero, the collector current 'I' increases rapidly to a saturation value, depending upon the value of base werent.
- * It may be noted that collector current Ic reaches to a satureation value when Vce 98 about 0.5 V.

- than the base current. Their small Ifp current 'Is' produces a large of a current Ic.
- iii) In cutoff region, when base current is two (IB=0), collector current is not zero (Ic#0), a small collector current exist called severse leakage current 'IcEO'.



Variation of Ic as a function of Is with constant 'Vee'. i.e. 'Ve' is held at a convenient level y Is is varied in Suitable steps and at each step Ic value is recorded. Ic is then plotted as a function of Io.

* A vertical line is drawn through a selected VCE value of the corresponding levels of Ic & IB are read along the line.

FEEDBACK

- In the feedback process a part of output is sampled and fed back to the input.
- The fed back signal can be in phase with or out of phase with the original input signal.

Definition of feedback:

- Feedback is defined as the process in which a part of output signal (voltage or current) is returned back to the input.
- The amplifier that operates on the principle of feedback is known as feedback amplifier.

TYPES OF FEEDBACK

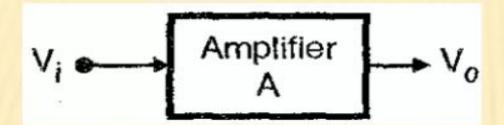
- Positive feedback
- 2. Negative feedback.

If the original input signal and the feedback signal are in phase, the feedback is called as positive feedback.

However if these two signals are out of phase then the feedback is called as negative feedback.

AMPLIFIER WITHOUT FEEDBACK

gative feedback , 🛭 unt 🛭 Current series 🗳

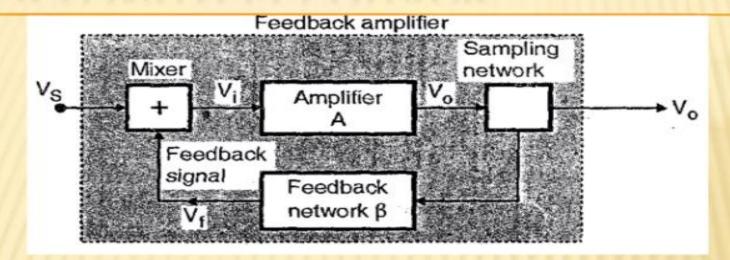


- The most important thing to understand from Fig. is that the output and input terminals of this amplifier are not connected to each other in any way.
- Therefore the amplifier of Fig. is an amplifier without any feedback,

Gain without feedback.

$$A = \frac{V_o}{V_i}$$

AMPLIFIER WITH FEEDBACK

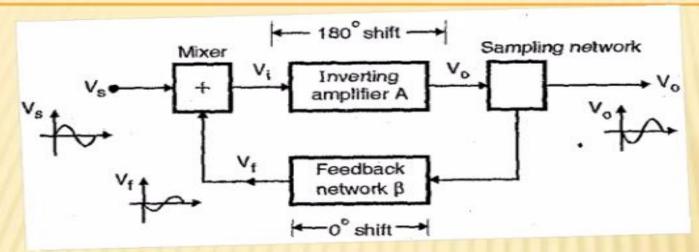


- Refer to Fig. Here the same amplifier with a gain A is being used along with a mixer network, sampling network and a feedback network.
- The voltage gain of the feedback amplifier is given by,

Gain with feedback

$$A_f = \frac{V_o}{V_S}$$

AMPLIFIER WITH A NEGATIVE FEEDBACK



The block diagram of an amplifier with a Negative Feedback Fig.

$$V_f = \beta V_o$$

Where V_f = Feedback signal (output of the feedback network)

Feedback factor
$$\beta = \frac{V_f}{V_o}$$

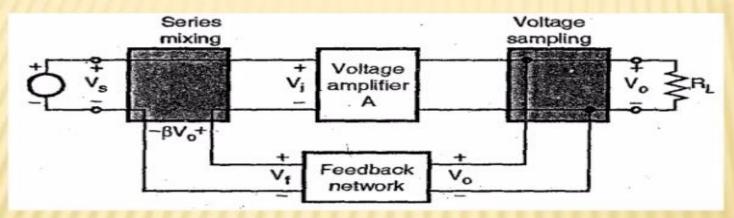
TYPES OF NEGATIVE FEEDBACK:

- Depending on the type of sampling and mixing networks, the feedback amplifiers are classified into four categories:
- Voltage series feedback
- Current series feedback
- Current shunt feedback
- Voltage shunt feedback

VOLTAGE SERIES FEEDBACK

Therefore,

voltage series feedback = voltage sampling + series mixing
The voltage series feedback is present in the voltage amplifiers.



A transistor amplifier which uses the voltage series feedback is the common collector or emitter follower amplifier:

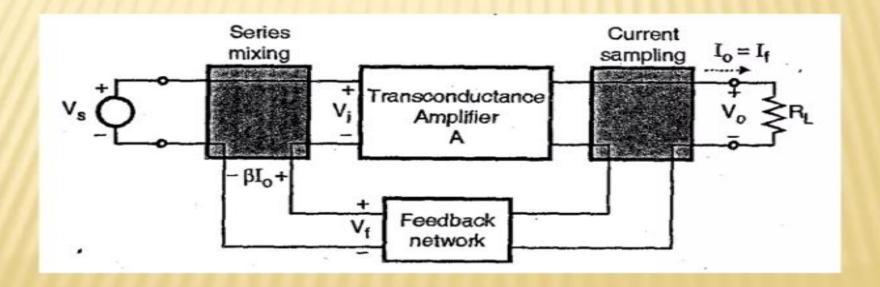
- 1. A common collector (or emitter follower) amplifier using BJT.
- 2. A common drain (or source follower) amplifier using FET.

CURRENT SERIES FEEDBACK

Therefore

Current sampling + Series mixing.

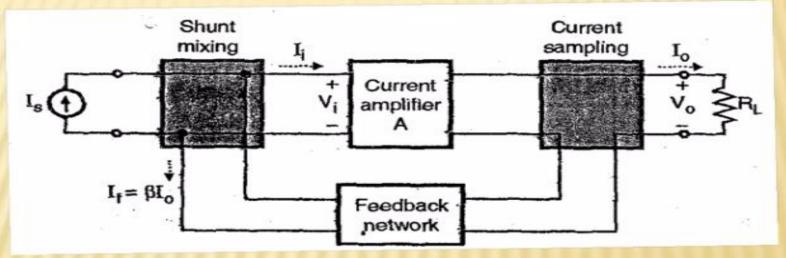
Current series feedback is present in the transconductance amplifiers.



CURRENT SHUNT FEEDBACK:

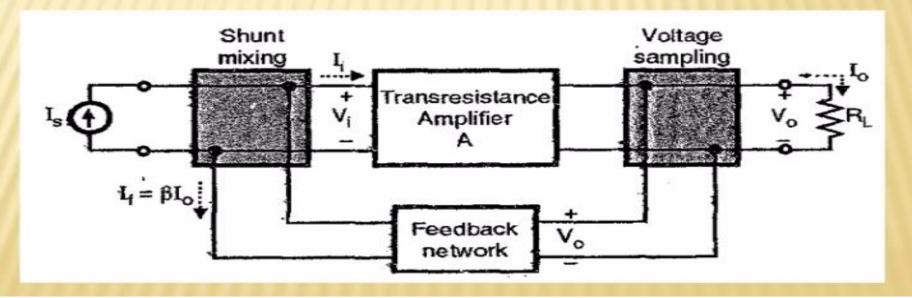
This is a combination of current sampling and shunt mixing. The block diagram of a feedback amplifier with current shunt feedback is shown in Fig.

Current sampling + Shunt mixing



Current shunt feedback is present in the current amplifiers.

- U
- The block diagram of an amplifier with voltage shunt feedback amplifier is shown in Fig.
 - Voltage Shunt Feedback = Voltage Sampling + Shunt Mixing.
- The voltage shunt feedback is present in the transresistance amplifier.







Advantages

- Negative feedback stabilizes the gain of the amplifier.
- Input resistance increases for certain feedback configurations.
- Output resistance decreases for certain feedback configurations.
- Operating point is stabilized.

Disadvantages

- Reduction in gain.
- Reduction in input resistance in case of voltage shunt and current shunt type amplifiers.
- Increase in output resistance in case of current shunt and current series feedback amplifiers.

Applications of negative feedback

- In a1most all the electronic amplifiers.
- In the regulated power supplies.
- In wideband amplifiers (amplifiers having a large bandwidth)